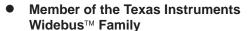
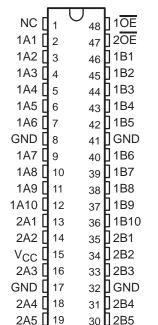
DGG, DGV, OR DL PACKAGE

(TOP VIEW)

SCDS166 - MAY 2004



- High-Bandwidth Data Path (Up To 500 MHz<sup>†</sup>)
- 5-V Tolerant I/Os with Device Powered Up or Powered Down
- Low and Flat ON-State Resistance (r<sub>on</sub>)
   Characteristics Over Operating Range (r<sub>on</sub> = 5 Ω Typical)
- Rail-to-Rail Switching on Data I/O Ports
   0-V to 5-V Switching With 3.3-V V<sub>CC</sub>
   0-V to 3.3-V Switching With 2.5-V V<sub>CC</sub>
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low Input/Output Capacitance Minimizes Loading and Signal Distortion (C<sub>io(OFF)</sub> = 4 pF Typical)
- Fast Switching Frequency (f<sub>OE</sub> = 20 MHz Max)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption (I<sub>CC</sub> = 1 mA Typical)
- V<sub>CC</sub> Operating Range From 2.3 V to 3.6 V
- Data I/Os Support 0 V to 5 V Signaling Levels (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- Supports Both Digital and Analog Applications: PCI Interface, Differential Signal Interface, Memory Interleaving, Bus Isolation, Low-Distortion Signal Gating
  - † For additional information regarding the performance characteristics of the CB3Q family, refer to the TI application report, CBT-C, CB3T, and CB3Q Signal-Switch Families, literature number SCDA008.



NC - No internal connection

29 **∏** 2B6

28 2B7

27 2B8

26 D2B9

25 D2B10

2A6  $\Pi$  20

2A9 **∏** 23

2A10 24

2A7 21

2A8 🛮 22



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#### SCDS166 - MAY 2004

### description/ordering information

The SN74CB3Q16210 is a high-bandwidth FET bus switch utilizing a charge pump to elevate the gate voltage of the pass transistor, providing a low and flat ON-state resistance (r<sub>on</sub>). The low and flat ON-state resistance allows for minimal propagation delay and supports rail-to-rail switching on the data input/output (I/O) ports. The device also features low data I/O capacitance to minimize capacitive loading and signal distortion on the data bus. Specifically designed to support high-bandwidth applications, the SN74CB3Q16210 provides an optimized interface solution ideally suited for broadband communications, networking, and data-intensive computing systems.

The SN74CB3Q16210 is organized as two 10-bit bus switches with separate output-enable  $(1\overline{OE}, 2\overline{OE})$  inputs. It can be used as two 10-bit bus switches or as one 20-bit bus switch. When  $\overline{OE}$  is low, the associated 10-bit bus switch is ON and the A port is connected to the B port, allowing bidirectional data flow between ports. When  $\overline{OE}$  is high, the associated 10-bit bus switch is OFF, and a high-impedance state exists between the A and B ports.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry prevents damaging current backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### ORDERING INFORMATION

TA	PACKA	GEŤ	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
	0000 0	Tube	SN74CB3Q16210DL	000040040		
4000 / 0500	SSOP – DL	Tape and reel	SN74CB3Q16210DLR	CB3Q16210		
-40°C to 85°C	TSSOP – DGG	Tape and reel	SN74CB3Q16210DGGR	CB3Q16210		
	TVSOP - DGV	Tape and reel	SN74CB3Q16210DGVR	BW210		

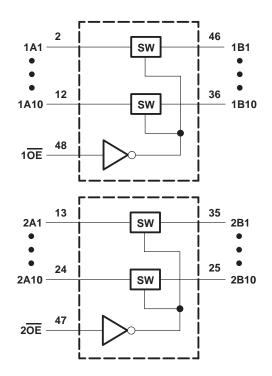
<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

# FUNCTION TABLE (each 10-bit bus switch)

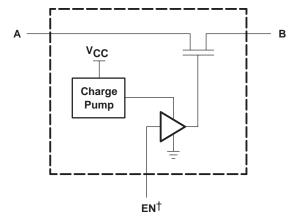
INPUT OE	INPUT/OUTPUT A	FUNCTION
L	В	A port = B port
Н	Z	Disconnect



# logic diagram (positive logic)



## simplified schematic, each FET switch (SW)



<sup>†</sup>EN is the internal enable signal applied to the switch.



## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub> (see Note 1)	–0.5 V to 4.6 V
Control input voltage range, V <sub>IN</sub> (see Notes 1 and 2)	$\dots$ -0.5 V to 7 V
Switch I/O voltage range, V <sub>I/O</sub> (see Notes 1, 2, and 3)	$\dots$ -0.5 V to 7 V
Control input clamp current, I <sub>IK</sub> (V <sub>IN</sub> < 0)	–50 mA
I/O port clamp current, $I_{I/OK}$ ( $V_{I/O}$ < 0)	–50 mA
ON-state switch current, I <sub>I/O</sub> (see Note 4)	±64 mA
Continuous current through V <sub>CC</sub> or GND terminals	±100 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 5): DGG package	70°C/W
DGV package	58°C/W
DL package	63°C/W
Storage temperature range, T <sub>sto</sub>	. −65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to ground unless otherwise specified.
  - 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
  - 3. V<sub>I</sub> and V<sub>O</sub> are used to denote specific conditions for V<sub>I/O</sub>.
  - 4. II and IO are used to denote specific conditions for II/O.
  - 5. The package thermal impedance is calculated in accordance with JESD 51-7.

## recommended operating conditions (see Note 6)

			MIN	MAX	UNIT
Vcc	Supply voltage		2.3	3.6	V
.,		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7	5.5	.,
VIH	High-level control input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2	5.5	V
.,		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	.,
$V_{IL}$	Low-level control input voltage	V <sub>CC</sub> = 2.7 V to 3.6 V	0	8.0	V
V <sub>I/O</sub>	Data input/output voltage		0	5.5	V
TA	Operating free-air temperature		-40	85	°C

NOTE 6: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PAF	RAMETER		TEST CONDITION	IS	MIN	TYP <sup>†</sup>	MAX	UNIT
VIK		V <sub>CC</sub> = 3.6 V,	$I_{I} = -18 \text{ mA}$				-1.8	V
I <sub>IN</sub>	Control inputs	V <sub>CC</sub> = 3.6 V,	$V_{IN} = 0 \text{ to } 5.5 \text{ V}$				±1	μΑ
loz‡		V <sub>CC</sub> = 3.6 V,	$V_O = 0 \text{ to } 5.5 \text{ V},$ $V_I = 0,$	Switch OFF, V <sub>IN</sub> = V <sub>CC</sub> or GND			±1	μΑ
l <sub>off</sub>		$V_{CC} = 0$ ,	$V_0 = 0 \text{ to } 5.5 \text{ V},$	V <sub>I</sub> = 0			1	μΑ
lcc		V <sub>CC</sub> = 3.6 V,	I <sub>I/O</sub> = 0, Switch ON or OFF,	$V_{IN} = V_{CC}$ or GND		1	3	mA
∆l <sub>CC</sub> §	Control inputs	V <sub>CC</sub> = 3.6 V,	One input at 3 V,	Other inputs at V <sub>CC</sub> or GND			30	μΑ
<sup>I</sup> CCD <sup>¶</sup>	Per control input	V <sub>CC</sub> = 3.6 V,	A and B ports open, Control input switching		0.15	0.25	mA/ MHz	
C <sub>in</sub>	Control inputs	V <sub>CC</sub> = 3.3 V,	V <sub>IN</sub> = 5.5 V, 3.3 V, or	0		3.5	5	pF
C <sub>io(OFF</sub>	=)	V <sub>CC</sub> = 3.3 V,	Switch OFF, V <sub>IN</sub> = V <sub>CC</sub> or GND,	V <sub>I/O</sub> = 5.5 V, 3.3 V, or 0		4	5	pF
C <sub>io(ON)</sub>	)	V <sub>CC</sub> = 3.3 V,	Switch ON, V <sub>IN</sub> = V <sub>CC</sub> or GND,	V <sub>I/O</sub> = 5.5 V, 3.3 V, or 0		10	12.5	pF
		$V_{CC} = 2.3 \text{ V},$	$V_{I} = 0,$	$I_O = 30 \text{ mA}$		5	8	
#		TYP at $V_{CC} = 2.5 \text{ V}$	V <sub>I</sub> = 1.7 V,	$I_{O} = -15 \text{ mA}$		5	9	Ω
r <sub>on</sub> #		Vac - 2 V	$V_{I} = 0,$	I <sub>O</sub> = 30 mA		5	7	22
		VCC = 3 V	V <sub>I</sub> = 2.4 V,	I <sub>O</sub> = -15 mA		5	9	

NOTE 7: V<sub>IN</sub> and I<sub>IN</sub> refer to control inputs. V<sub>I</sub>, V<sub>O</sub>, I<sub>I</sub>, and I<sub>O</sub> refer to data pins.

# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	TO	V <sub>CC</sub> =	2.5 V 2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	
fOE	ŌĒ	A or B		10		20	MHz
t <sub>pd</sub> ☆	A or B	B or A		0.15		0.25	ns
t <sub>en</sub>	ŌE	A or B	1.5	9	1.5	8	ns
<sup>t</sup> dis	ŌĒ	A or B	1	8	1	7	ns

Il Maximum switching frequency for control input ( $V_O > V_{CC}$ ,  $V_I = 5$  V,  $R_L \ge 1$  M $\Omega$ ,  $C_L = 0$ )



 $<sup>^{\</sup>dagger}$  All typical values are at VCC = 3.3 V (unless otherwise noted), TA = 25  $^{\circ}$  C.

<sup>&</sup>lt;sup>‡</sup> For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.

<sup>§</sup> This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V<sub>CC</sub> or GND.

<sup>¶</sup> This parameter specifies the dynamic power-supply current associated with the operating frequency of a single control input (see Figure 2).

<sup>#</sup> Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

<sup>\*</sup>The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

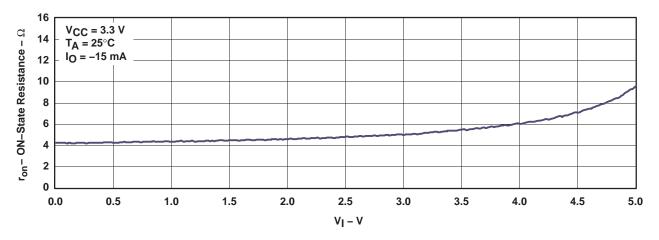


Figure 1. Typical  $r_{on}$  vs  $V_{I}$ 

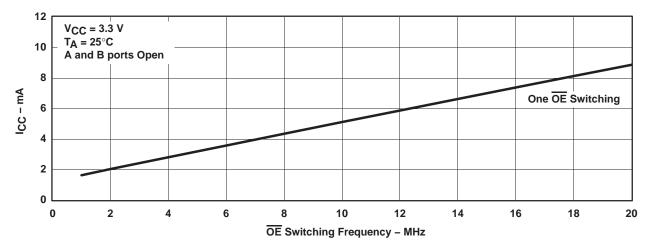
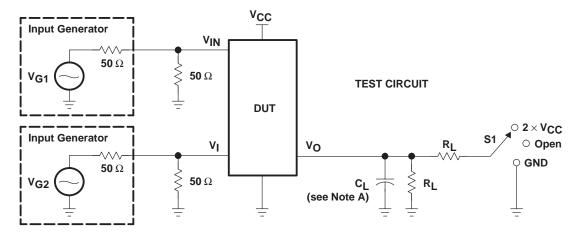


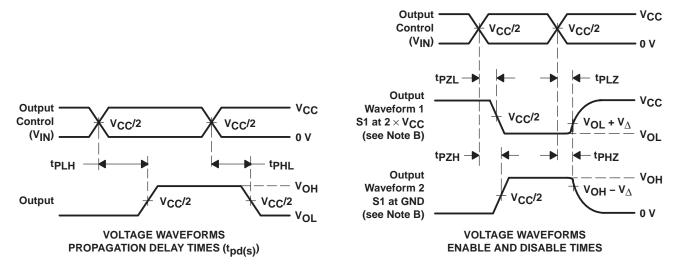
Figure 2. Typical I<sub>CC</sub> vs  $\overline{\text{OE}}$  Switching Frequency



#### PARAMETER MEASUREMENT INFORMATION



TEST	VCC	S1	RL	VI	CL	$v_{\!\scriptscriptstyle\Delta}$
<sup>t</sup> pd(s)	2.5 V $\pm$ 0.2 V	Open	500 Ω	V <sub>CC</sub> or GND	30 pF	
-pu(s)	3.3 V $\pm$ 0.3 V	Open	500 Ω	V <sub>CC</sub> or GND	50 pF	
tPLZ/tPZL	2.5 V ± 0.2 V	2×V <sub>CC</sub>	500 Ω	GND	30 pF	0.15 V
	3.3 V $\pm$ 0.3 V	2×V <sub>CC</sub>	500 Ω	GND	50 pF	0.3 V
4	2.5 V ± 0.2 V	GND	500 Ω	VCC	30 pF	0.15 V
tPHZ/tPZH	3.3 V $\pm$ 0.3 V	GND	500 Ω	VCC	50 pF	0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_Q = 50 \Omega$ ,  $t_f \leq 2.5 \text{ ns.}$
- D. The outputs are measured one at a time, with one transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd(s). The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Test Circuit and Voltage Waveforms



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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
74CB3Q16210DGVRG4	Active	Production	TVSOP (DGV)   48	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	BW210
74CB3Q16210DGVRG4.B	Active	Production	TVSOP (DGV)   48	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	BW210
SN74CB3Q16210DGGR	Active	Production	TSSOP (DGG)   48	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3Q16210
SN74CB3Q16210DGGR.B	Active	Production	TSSOP (DGG)   48	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3Q16210
SN74CB3Q16210DGVR	Active	Production	TVSOP (DGV)   48	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	BW210
SN74CB3Q16210DGVR.B	Active	Production	TVSOP (DGV)   48	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	BW210
SN74CB3Q16210DL	Active	Production	SSOP (DL)   48	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3Q16210
SN74CB3Q16210DL.B	Active	Production	SSOP (DL)   48	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3Q16210
SN74CB3Q16210DLR	Active	Production	SSOP (DL)   48	1000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3Q16210
SN74CB3Q16210DLR.B	Active	Production	SSOP (DL)   48	1000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3Q16210

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



## **PACKAGE OPTION ADDENDUM**

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and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

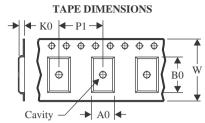
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74CB3Q16210DGVRG4	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1
SN74CB3Q16210DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
SN74CB3Q16210DGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1
SN74CB3Q16210DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1



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#### \*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74CB3Q16210DGVRG4	TVSOP	DGV	48	2000	353.0	353.0	32.0
SN74CB3Q16210DGGR	TSSOP	DGG	48	2000	356.0	356.0	45.0
SN74CB3Q16210DGVR	TVSOP	DGV	48	2000	353.0	353.0	32.0
SN74CB3Q16210DLR	SSOP	DL	48	1000	356.0	356.0	53.0

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74CB3Q16210DL	DL	SSOP	48	25	473.7	14.24	5110	7.87
SN74CB3Q16210DL.B	DL	SSOP	48	25	473.7	14.24	5110	7.87

## DGV (R-PDSO-G\*\*)

#### **24 PINS SHOWN**

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



SMALL OUTLINE PACKAGE



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



## DGG (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE PACKAGE

#### **48 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

# DL (R-PDSO-G48)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

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